

Application Serial No. 10/738,399
Reply to Office Action of February 18, 2005

MAY 09 2005

PATENT
Docket: CU-3495**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

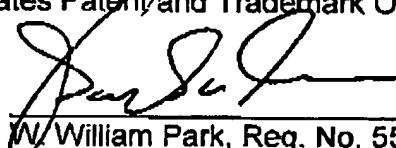
In re Application:	Sang Tae AHN et al.]	GRP ART UNIT: 2818
Serial No:	10/738,399]	Ex.: Lee, Calvin
Filed:	December 17, 2003]	
For:	METHOD FOR FABRICATING ISOLATION LAYER IN SEMICONDUCTOR DEVICE		

Certification under 37 C.F.R. §1.8(a)

The USPTO Central Fax No. (703) 872-9306

Date of Fax Transmittal: May 9, 2005

I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being transmitted to the United States Patent and Trademark Office to the fax number and on the date indicated above.



W. William Park, Reg. No. 55,523

AMENDMENT UNDER 37 CFR 1.111

Mail Stop Amendment
 The Commissioner for Patents
 P.O. Box 1450
 Alexandria VA 22313-1450

Sir:

In response to the Office Action dated February 18, 2005, setting a 3-month shortened statutory period for a reply ending on May 18, 2005, Applicants submit the following responsive amendment in the above-identified application. This amendment is considered to place the application in better condition for allowance.

No fee is believed to be required with this amendment, but, if this is not the case, please charge the requisite fee (or credit any overpayment) to Deposit Account No. 12-0400.

Amendments to the Specification begin on page 3 of this paper.

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Amendments to the Claims are reflected in the listing of claims, which begins
on page 4 of this paper.

Remarks/Arguments begin on page 9 of this paper.